



**THE DATASHEET OF
FZT653QTA**

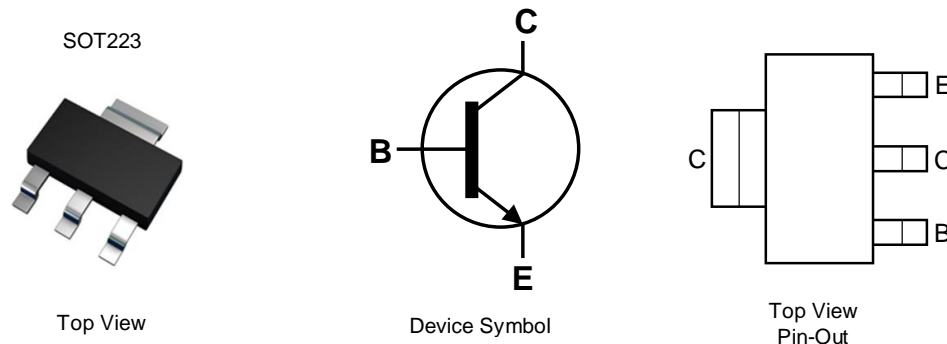


Features

- $BV_{CEO} > 100V$
- $I_C = 2A$ High Continuous Current
- $I_{CM} = 6A$ Peak Pulse Current
- Low Saturation Voltage $V_{CE(sat)} < 300mV @ 1A$
- Complementary PNP Type: FZT753
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The DIODES™ FZT653Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**
<http://www.diodes.com/quality/product-definitions/>

Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 ③
- Weight: 0.112 grams (Approximate)

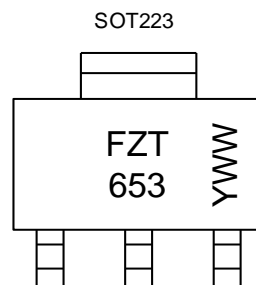


Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Peel
FZT653QTA	Automotive	FZT653	7	12	1,000

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



FZT 653 = Product Type Marking Code
 YWW = Date Code Marking
 Y or \bar{Y} = Last Digit of Year (ex: 8 = 2018)
 WW or $\bar{W}W$ = Week Code (01 to 53)

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	120	V
Collector-Emitter Voltage	V _{CEO}	100	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	I _C	2	A
Peak Pulse Current	I _{CM}	6	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

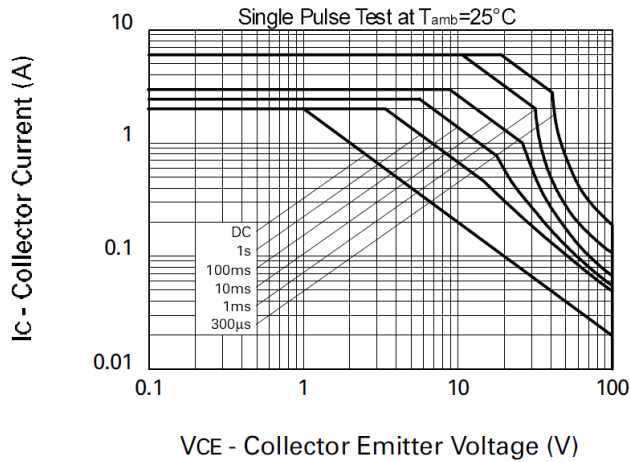
Characteristic	Symbol	Value	Unit	
Power Dissipation	P _D	(Note 5)	3	W
		(Note 6)	2	
		(Note 7)	1.6	
		(Note 8)	1.2	
Thermal Resistance, Junction to Ambient	R _{θJA}	(Note 5)	41.7	°C/W
		(Note 6)	62.5	
		(Note 7)	78.1	
		(Note 8)	104	
Thermal Resistance Junction to Lead	R _{θJL}	12.9		
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 10)

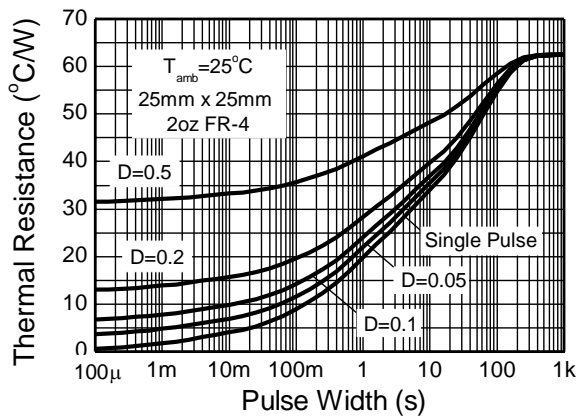
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
5. For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 6. Same as Note 6, except the device is mounted on 25mm x 25mm 2oz copper.
 7. Same as Note 6, except the device is mounted on 25mm x 25mm 1oz copper.
 8. Same as Note 6, except the device is mounted on minimum recommended pad layout.
 9. Thermal resistance from junction to solder-point (at the end of the collector lead).
 10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

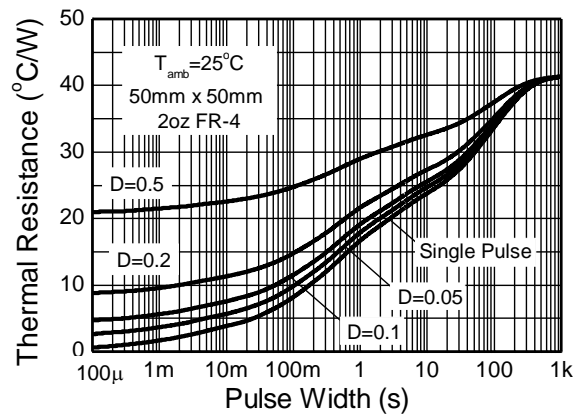
Thermal Characteristics and Derating Information



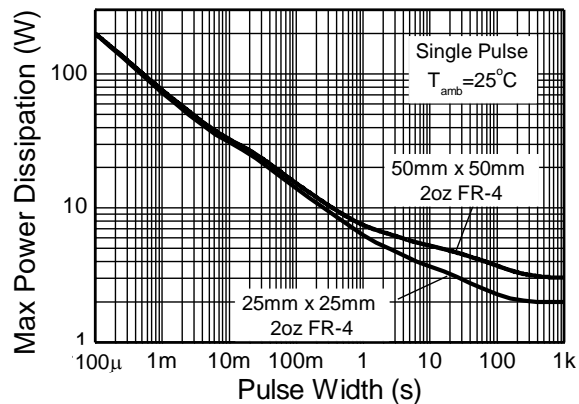
Safe Operating Area



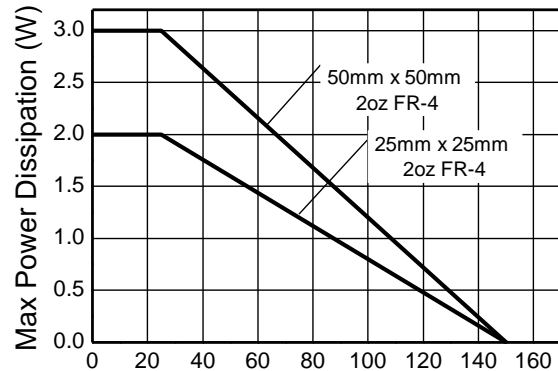
Transient Thermal Impedance



Transient Thermal Impedance



Pulse Power Dissipation



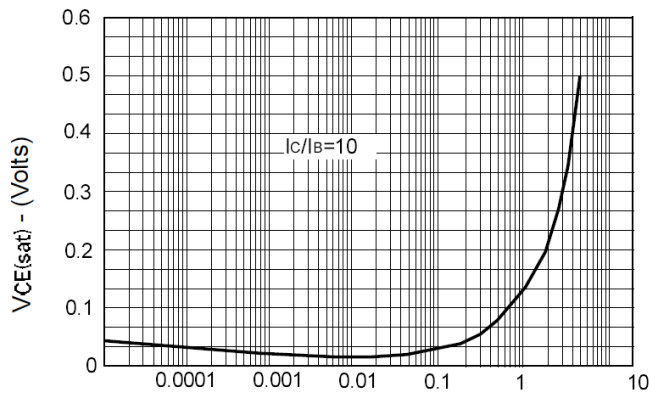
Derating Curve

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	120	–	–	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	100	–	–	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	–	–	V	I _E = 100μA
Collector Cut-Off Current	I _{CBO}	–	1	100	nA	V _{CB} = 100V
		–	–	10	μA	V _{CB} = 100V, T _A = +125°C
Emitter Cut-Off Current	I _{EBO}	–	1	100	nA	V _{EB} = 5.6V
Collector-Emitter Saturation Voltage (Note 11)	V _{CE(sat)}	–	0.13	0.3	V	I _C = 1A, I _B = 100mA
		–	0.23	0.5		I _C = 2A, I _B = 200mA
Base-Emitter Saturation Voltage (Note 11)	V _{BE(sat)}	–	0.9	1.25	V	I _C = 1A, I _B = 100mA
Base-Emitter Turn-On Voltage (Note 11)	V _{BE(on)}	–	0.8	1.0	V	I _C = 1A, V _{CE} = 2V
DC Current Gain (Note 11)	h _{FE}	70	200	–	–	I _C = 50mA, V _{CE} = 2V
		100	200	300		I _C = 500mA, V _{CE} = 2V
		55	110	–		I _C = 1A, V _{CE} = 2V
		25	55	–		I _C = 2A, V _{CE} = 2V
Current Gain-Bandwidth Product	f _T	140	175	–	MHz	V _{CE} = 5V, I _C = 100mA, f = 100MHz
Switching Times	t _{on}	–	80	–	ns	I _C = 500mA, V _{CC} = 10V, I _{B1} = -I _{B2} = 50mA
	t _{off}	–	1200	–		
Output Capacitance	C _{obo}	–	–	30	pF	V _{CB} = 10V, f = 1MHz

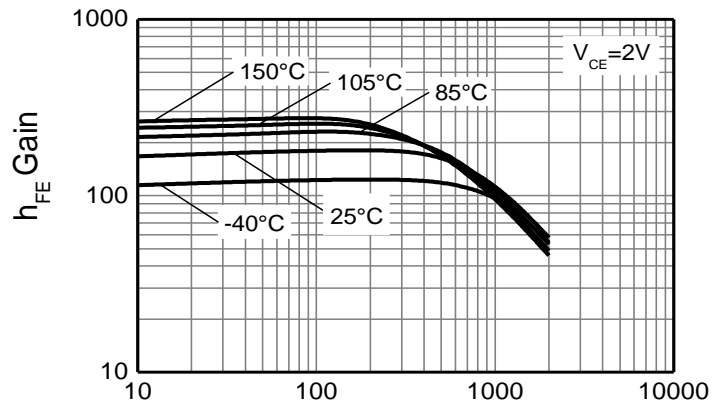
Note: 11. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



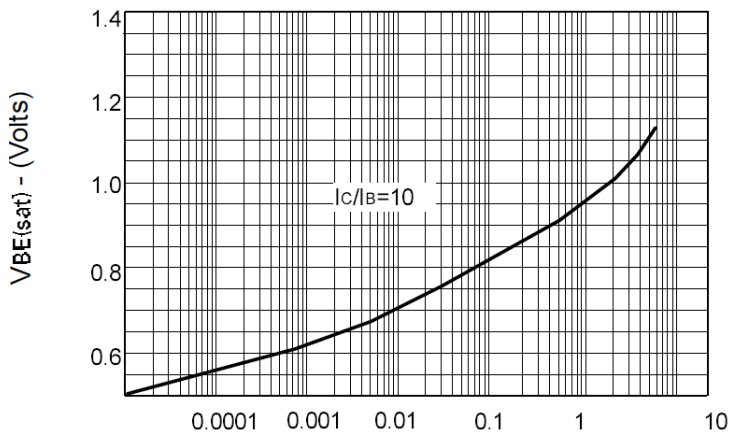
I_C - Collector Current (Amps)

VCE(sat) v I_C



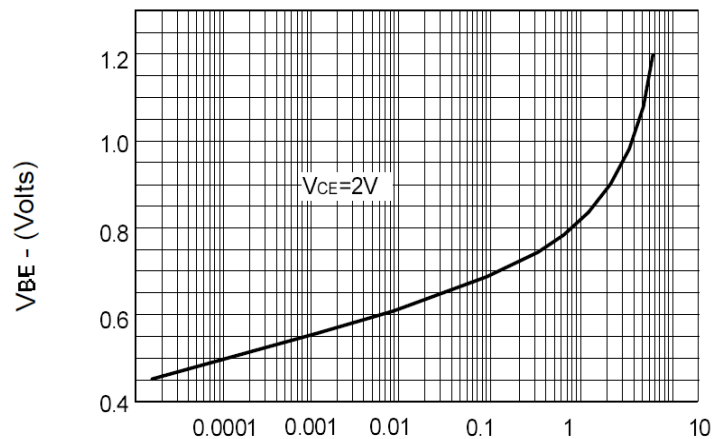
I_C - Collector Current (mA)

h_{FE} v I_C



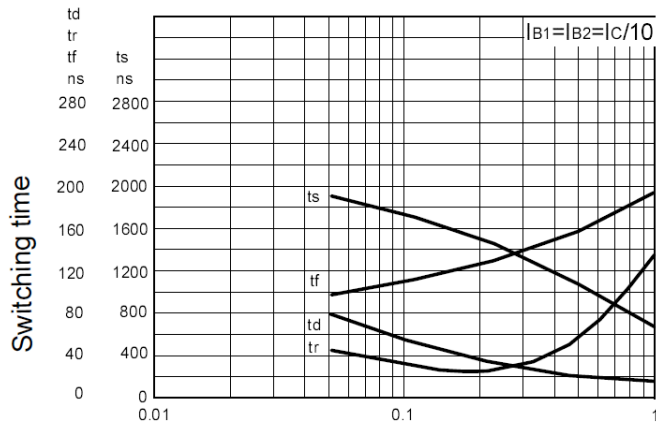
I_C - Collector Current (Amps)

VBE(sat) v I_C



I_C - Collector Current (Amps)

VBE(on) v I_C



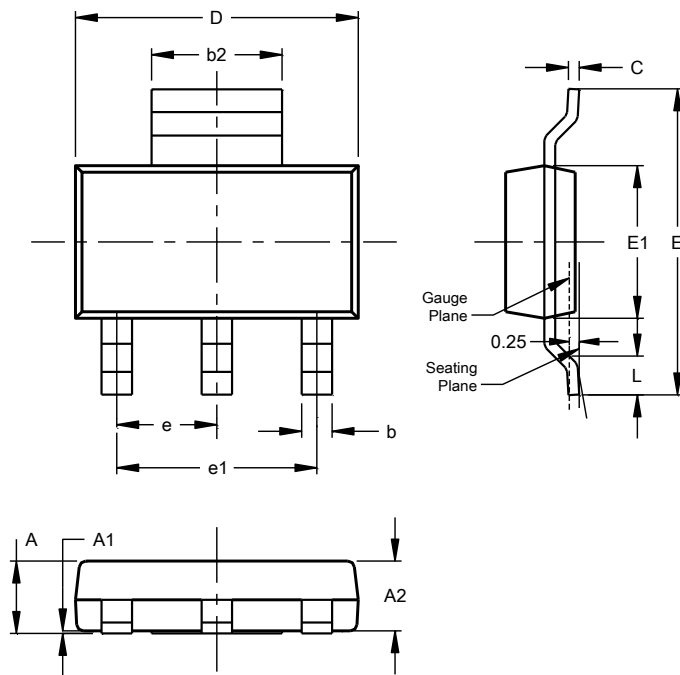
I_C - Collector Current (Amps)

Switching Speeds

Package Outline Dimensions

Please see <https://www.diodes.com/design/support/packaging/> for the latest version.

SOT223 (Type DN)

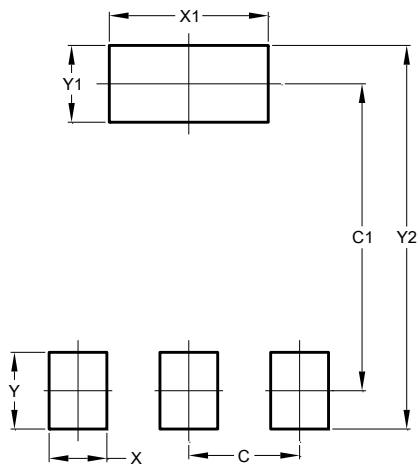


SOT223 (Type DN)			
Dim	Min	Max	Typ
A	--	1.70	--
A1	0.01	0.15	--
A2	1.50	1.68	1.60
b	0.60	0.80	0.70
b2	2.90	3.10	--
c	0.20	0.32	--
D	6.30	6.70	--
E	6.70	7.30	--
E1	3.30	3.70	--
e	--	--	2.30
e1	--	--	4.60
L	0.85	--	--
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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